General Description

Applications

The MAX4599 single-pole/double-throw (SPDT) switch operates from a +2.0V to +5.5V single supply. It offers 60 Ω max on-resistance (R_{ON}) at +5V and fast switching times (t_{ON} = 30ns max, t_{OFF} = 25ns max).

The MAX4599 features excellent R_{ON} flatness (4 Ω max) and matching (1 Ω max) between channels. This device also offers 5pC max charge injection.

The MAX4599 is available in tiny 6-pin SC70, $\mu\text{DFN},$ and SOT23 packages.

Battery-Operated Equipment Audio and Video Signal Routing

Sample-and-Hold Circuits Communications Circuits

Low-Voltage Data-Acquisition Systems

Cellular Phones

Features

- ♦ Available in 6-Pin SC70 Package
- 60Ω max (40Ω typ) On-Resistance
- 1Ω max (0.2Ω typ) R_{ON} Matching Between Channels
- 4Ω max (2.5Ω typ) Ron Flatness
- Fast Switching: t_{ON} = 30ns (max) t_{OFF} = 25ns (max)
- Guaranteed 5pC max Charge Injection
- ♦ +2.0V to +5.5V Single-Supply Operation
- 200MHz -3dB Bandwidth
- Low ±0.5nA Leakage Current at +25°C
- Break-Before-Make Switching
- ◆ TTL/CMOS-Logic Compatible
- ♦ -76dB Off-Isolation at 1MHz
- 0.12% Total Harmonic Distortion

Ordering Information

PART	TEMP RANGE	PIN- PACKAGE	TOP MARK
MAX4599EXT-T	-40°C to +85°C	6 SC70-6	AAF
MAX4599EUT-T	-40°C to +85°C	6 SOT23-6	AAHC
MAX4599ELT-T	-40°C to +85°C	6 µDFN-6	AA

Pin Configuration/Functional Diagram/Truth Table



_ Maxim Integrated Products 1

6 es MAX4599

For pricing, delivery, and ordering information, please contact Maxim/Dallas Direct! at 1-888-629-4642, or visit Maxim's website at www.maxim-ic.com.

ABSOLUTE MAXIMUM RATINGS

Voltage Referenced to GND

V+	0.3V to +6V
IN, COM, NO, NC (Note 1)	0.3V to (V+ + 0.3V)
Continuous Current (any terminal)	±20mA
Peak Current, COM, NO, NC	
(pulsed at 1ms, 10% duty cycle)	±40mA

Continuous Power Dissipation ($T_A = +70^{\circ}C$)	
6-Pin SC70-6 (derate 3.1mW/°C above +70°C)245	mW
6-Pin µDFN-6 (derate 2.1mW/°C above +70°C)	mW
6-Pin SOT23-6 (derate 7.1mW/°C above +70°C)571	mW
Operating Temperature Range	
MAX4599E_T40°C to +8	5°C
Storage Temperature Range65°C to +15	0°C
Lead Temperature (soldering, 10s)+30	0°C

Note 1: Signals on NO, NC, COM, or IN exceeding V+ or GND are clamped by internal diodes. Limit forward-diode current to maximum current rating.

Stresses beyond those listed under "Absolute Maximum Ratings" may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated in the operational sections of the specifications is not implied. Exposure to absolute maximum rating conditions for extended periods may affect device reliability.

ELECTRICAL CHARACTERISTICS— Single +5V Supply

 $(V + = +4.5V \text{ to } +5.5V, V_{INH} = +2.4V, V_{INL} = +0.8V, T_A = T_{MIN} \text{ to } T_{MAX}$, unless otherwise noted.) (Notes 2, 3)

PARAMETER	SYMBOL	CONDITIONS		MIN	ТҮР	MAX	UNITS	
ANALOG SWITCH			Ľ					
Analog Signal Range	V _{COM} , V _{NO} , V _{NC}			0		V+	V	
On-Resistance	Ron	$V_{+} = 4.5V, I_{COM} = 1mA,$	$T_A = +25^{\circ}C$		40	60	Ω	
		$V_{NO} \text{ or } V_{NC} = 3.5V$	$T_A = T_{MIN}$ to T_{MAX}			65		
On-Resistance Match Between	ABON	$V + = 4.5V$, $I_{COM} = 1A$,	$T_A = +25^{\circ}C$		0.2	1	Q	
Channels (Note 4)	Анон	$V_{NO} \text{ or } V_{NC} = 3.5 V$	$T_A = T_{MIN}$ to T_{MAX}			2		
On-Resistance Flatness		$V_{+} = 4.5V; I_{COM} = 1mA;$ $V_{NO} \text{ or } V_{NC} = 1V_{-}2.0V$	T _A = +25°C		2.5	4	Q	
(Note 5)		3.5V T _A =	$T_A = T_{MIN}$ to T_{MAX}			5	25	
NO, NC Off-Leakage Current	I _{NO(OFF)} ,	$V_{A} = 5.5V; V_{COM} = 1V, T_{A} = +25^{\circ}C$	$T_A = +25^{\circ}C$	-0.5	0.01	0.5	nA	
(Note 6)	INC(OFF)	1V	$T_A = T_{MIN}$ to T_{MAX}	-5		5		
COM On-Leakage Current			$V_{+} = 5.5V; V_{COM} = 1V,$ 4.5V: VNO or VNC = 1V	$T_A = +25^{\circ}C$	-1	0.01	1	nA
(Note 6)		4.5V, or floating	$T_A = T_{MIN}$ to T_{MAX}	-10		10		
DIGITAL I/O								
Input Logic High	VIH			2.4			V	
Input Logic Low	VIL					0.8	V	
DYNAMIC								
Turn-On Time	ton	$V_{NO}, V_{NC} = 3V;$	$T_A = +25^{\circ}C$		25	30	ns	
	UN	Figure 2	$T_A = T_{MIN}$ to T_{MAX}			40	110	

ELECTRICAL CHARACTERISTICS—Single +5V Supply (continued)

(V+ =+4.5V to +5.5V, V_{INH} = +2.4V, V_{INL} = +0.8V, $T_A = T_{MIN}$ to T_{MAX} , unless otherwise noted.) (Notes 2, 3)

PARAMETER	SYMBOL	CONDITIONS		MIN	ТҮР	MAX	UNITS
Turn-Off Time	torr	V_{NO} , $V_{NC} = 3V$; BL = 1kO: CL = 35pE:	$T_A = +25^{\circ}C$		20	25	ne
	UFF	Figure 2	$T_A = T_{MIN}$ to T_{MAX}			30	115
Broak-Before-Make	tooM	V_{NO} , $V_{NC} = 3V$; BL = 1kO: CL = 35pE:	$T_A = +25^{\circ}C$		10		ne
Dieak-Deiole-Make	'BBIM	Figure 3	$T_A = T_{MIN}$ to T_{MAX}	1			115
On-Channel -3dB Bandwidth	BW	Signal = 0dBm, 50 Ω in and out, Figure 5	$T_A = +25^{\circ}C$		200		MHz
Off-Isolation (Note 7)	VISO	$\begin{array}{l} C_L = 5 p F; \ R_L = 50 \Omega; \\ f = 1 M Hz; \ V_{NO}, \ V_{NC} = \\ 1 V_{RMS}; \ Figure \ 5 \end{array}$	T _A = +25°C		-76		dB
Charge Injection (Note 6)	Q	$V_{GEN} = 0$, $R_{GEN} = 0$, $C_L = 1.0$ nF, Figure 4	$T_A = +25^{\circ}C$		3	5	рС
NO, NC Off-Capacitance	C _{NO(OFF}), C _{NC(OFF})	V _{NO} , V _{NC} = GND; f = 1MHz; Figure 6	T _A = +25°C		8		pF
COM Off-Capacitance	C _{COM} (OFF)	V _{COM} = GND, f = 1MHz, Figure 6	T _A = +25°C		8		pF
Switch On-Capacitance	C _(ON)	$V_{COM} = V_{NO},$ $V_{NC} = GND, f = 1MHz,$ Figure 6	T _A = +25°C		20		рF
Total Harmonic Distortion	THD	$\label{eq:RL} \begin{split} R_{L} &= 600 \Omega, \ V_{IN} = 5 V p\text{-} p, \\ f &= 20 H z \text{ to } 20 k H z \end{split}$	$T_A = +25^{\circ}C$		0.12		%
SUPPLY							
Power-Supply Range	V+			2.0		5.5	V
Positive Supply Current	+	$V + = 5.5V, V_{IN} = 0 \text{ or } V +$		-1	0.001	1	μA

ELECTRICAL CHARACTERISTICS—Single +3V Supply

(V+ = +2.7V to +3.6V, V_{INH} = +2.0V, V_{INL} = +0.8V, T_A =T_{MIN} to T_{MAX}, unless otherwise noted.) (Notes 2, 3)

PARAMETER	SYMBOL	CONDITIONS		MIN	ТҮР	MAX	UNITS
ANALOG SWITCH							
Analog Signal Range	V _{COM} , V _{NO} , V _{NC}			0		V+	V
On Bosistanco	Pou	$V + = 2.7V$, $I_{COM} = 1mA$,	$T_A = +25^{\circ}C$		60	95	0
On-nesistance	NON	$V_{NO} \text{ or } V_{NC} = 1V$	$T_A = T_{MIN}$ to T_{MAX}			105	52
DIGITAL I/O							
Input Logic High	VIH			2.0			V
Input Logic Low	VIL					0.8	V

M/IXI/M

ELECTRICAL CHARACTERISTICS—Single +3V Supply (continued)

 $(V + = +2.7V \text{ to } +3.6V, V_{INH} = +2.0V, V_{INL} = +0.8V, T_A = T_{MIN} \text{ to } T_{MAX}, \text{ unless otherwise noted.})$ (Notes 2, 3)

PARAMETER	SYMBOL	CONDITIONS		MIN	TYP	MAX	UNITS
DYNAMIC							
Turn-On Time	ton	V_{NO} , $V_{NC} = 2V$; B _L = 1kO: C _L = 35pE:	$T_A = +25^{\circ}C$		40	45	ns
	UN	Figure 2	$T_A = T_{MIN}$ to T_{MAX}			55	
Turp-Off Time	torr	$V_{NO}, V_{NC} = 2V;$	$T_A = +25^{\circ}C$		30	35	20
	UFF	Figure 2	$T_A = T_{MIN}$ to T_{MAX}			40	113
Broak Boforo Mako	tooM	V_{NO} , $V_{NC} = 2V$; $P_{L} = 1kO$; $C_{L} = 35pE$;	$T_A = +25^{\circ}C$		13		20
Dieak-Deloie-Wake	rbbin	Figure 3	$T_A = T_{MIN}$ to T_{MAX}	1			115
Charge Injection (Note 6)	Q	$V_{GEN} = 0$, $R_{GEN} = 0$, $C_L = 1.0$ nF, Figure 4	$T_A = +25^{\circ}C$		2	5	рС
SUPPLY							
Positive Supply Current	l+	$V + = 3.6V, V_{IN} = 0 \text{ or } V +$		-1	0.001	1	μA

ELECTRICAL CHARACTERISTICS—Single +2.5V Supply

 $(V + = +2.5V, V_{INH} = +2.0V, V_{INL} = +0.6V, T_A = T_{MIN}$ to T_{MAX} , unless otherwise noted.) (Notes 2, 3)

PARAMETER	SYMBOL	CONDITIONS		MIN	ТҮР	MAX	UNITS
ANALOG SWITCH			·				
Analog Signal Range	V _{COM} , V _{NO} , V _{NC}			0		V+	V
On-Besistance	BON	$V + = 2.5V, I_{COM} = 1mA,$	$T_A = +25^{\circ}C$		65	110	0
On nesistance	HON	$V_{NO} \text{ or } V_{NC} = 1V$	$T_A = T_{MIN}$ to T_{MAX}			120	52
Input Logic High	VIH			2.0			V
Input Logic Low	VIL					0.6	V
DYNAMIC	•						
Turn-On Time	ton	$\label{eq:VNO} \begin{array}{l} V_{NO}, V_{NC} = 2V; \\ R_L = 1 k \Omega; C_L = 35 p F; \\ Figure 3 \end{array}$	$T_A = +25^{\circ}C$		45	50	ns
	UN		$T_A = T_{MIN}$ to T_{MAX}			60	113
	tore	V_{NO} , $V_{NC} = 2V$; BL = 1kO: CL = 35pE:	$T_A = +25^{\circ}C$		30	35	ns
	UFF	Figure 3 $P_{L} = 35pF;$	$T_A = T_{MIN}$ to T_{MAX}			45	115

Note 2: Parameters are 100% tested at +25°C only and guaranteed by correlation at the full rated temperature.

Note 3: The algebraic convention, where the most negative value is a minimum and the most positive value a maximum, is used in this data sheet.

M/IXI/M

Note 4: $\Delta R_{ON} = R_{ON}(MAX) - R_{ON}(MIN)$.

Note 5: Flatness is defined as the difference between the maximum and minimum value of on-resistance as measured over the specified analog signal ranges.

Note 6: Guaranteed by design.

Note 7: Off-Isolation = $20\log_{10}$ (V_{COM} / V_{NO}), V_{COM} = output, V_{NO} = input to off switch.

Typical Operating Characteristics





Typical Operating Characteristics (continued)

Pin Description

	1	
PIN	NAME	FUNCTION
1	IN	Digital Control Input
2	V+	Positive Supply Voltage
3	GND	Ground
4	NC	Analog Switch Normally Closed
5	COM	Analog Switch Common
6	NO	Analog Switch Normally Open

Applications Information

Analog Signal Levels

Analog signals can range over the supply voltage (V+ to GND) with on-resistance changing very little over the entire range (see Typical Operating Characteristics). The MAX4599 is bidirectional, so the NO, NC, and COM pins can be used either as inputs or outputs.

Power-Supply Sequencing and Overvoltage Protection

Proper power-supply sequencing is recommended for all CMOS devices. Always apply V+ before applying analog signals or logic inputs, especially if the analog or logic signals are not current limited. If this sequencing is not possible, and if the analog or logic inputs are not current limited to < 20mA, add a small-signal diode (D1) as shown in Figure 1. If the analog signal can dip below GND, add D2. Adding protection diodes

TOTAL HARMONIC DISTORTION PLUS **NOISE vs. FREQUENCY**

Figure 1. Overvoltage Protection Using Two External Blocking Diodes

reduces the analog signal range to a diode drop (about 0.7V) below V+ for D1 or to a diode drop above ground for D2. The addition of diodes does not affect leakage. On-resistance increases by a small amount at low supply voltages. Maximum supply voltage (V+) must not exceed 6V.

Protection diodes D1 and D2 also protect against some overvoltage situations. A fault voltage up to the absolute maximum rating at an analog signal input does not damage the device, even if the supply voltage is below the signal voltage.

Test Circuits/Timing Diagrams

MAX4599

7

Figure 2. Switching Time

Figure 5. Off-Isolation/On-Channel Bandwidth

Test Circuits/Timing Diagrams (continued)

Figure 6. Channel On/Off-Capacitance

Chip Information

TRANSISTOR COUNT: 89

Package Information

(The package drawing(s) in this data sheet may not reflect the most current specifications. For the latest package outline information go to **www.maxim-ic.com/packages**.)

///XI/M

MAX4599

Package Information (continued)

(The package drawing(s) in this data sheet may not reflect the most current specifications. For the latest package outline information go to <u>www.maxim-ic.com/packages</u>.)

Maxim cannot assume responsibility for use of any circuitry other than circuitry entirely embodied in a Maxim product. No circuit patent licenses are implied. Maxim reserves the right to change the circuitry and specifications without notice at any time.

Maxim Integrated Products, 120 San Gabriel Drive, Sunnyvale, CA 94086 408-737-7600 _

© 2004 Maxim Integrated Products

cts Printed USA

MAXIM is a registered trademark of Maxim Integrated Products.

_ 9